

RJK6026DPE-00#J3

RJK6026DPE-00#J3 Information

www.undischer.com		RJK6026DPE-00#J3 Renesas Electronics America Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	
	Description	MOSFET N-CH 600V 5A LDPAK	11111
	Package	SC-83	
		For the pricing/inventory/lead time, please contact	E194444954
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



RJK6026DPE-00#J3 Specifications

Manufacturer Part Number	RJK6026DPE-00#J3
Manufacturer	Renesas Electronics America
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	SC-83
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	600V
Current - Continuous Drain (Id) @ 25°C	5A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	-
Gate Charge (Qg) (Max) @ Vgs	14nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	440pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	62.5W (Tc)
Rds On (Max) @ Id, Vgs	2.4 Ohm @ 2.5A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	4-LDPAK
Package / Case	SC-83
	Report errors?

RJK6026DPE-00#J3 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

RJK6026DPE-00#J3 Payment Methods





If you have any question about RJK6026DPE-00#J3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com